



LED Display Product Data Sheet LTG-1163M

Spec No.: DS30-2011-0177

Effective Date: 10/12/2011

Revision: -

LITE-ON DCC

RELEASE

BNS-OD-FC001/A4

LED DISPLAY

LTG-1163M
DATA SHEET

ITEM	DESCRIPTION	ISSUER	DATE
1	New spec	Erin Cheng	07/11/2011
2	Add Iv data and modify pin	Erin Cheng	07/15/2011
3	Modify REF	Erin Cheng	09/20/2011

FEATURES

- * 0.32 inch (8.14 mm) DIGIT HEIGHT
- * CONTINUOUS UNIFORM SEGMENTS
- * LOW POWER REQUIREMENT
- * EXCELLENT CHARACTERS APPEARANCE
- * HIGH BRIGHTNESS & HIGH CONTRAST
- * WIDE VIEWING ANGLE
- * SOLID STATE RELIABILITY
- * **LEAD-FREE PACKAGE(ACCORDING TO ROHS)**

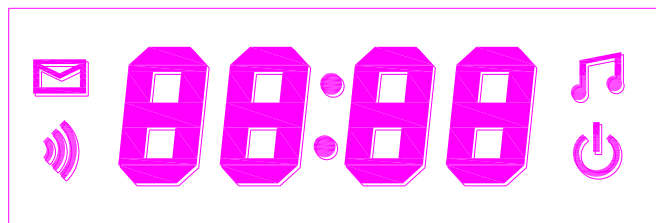
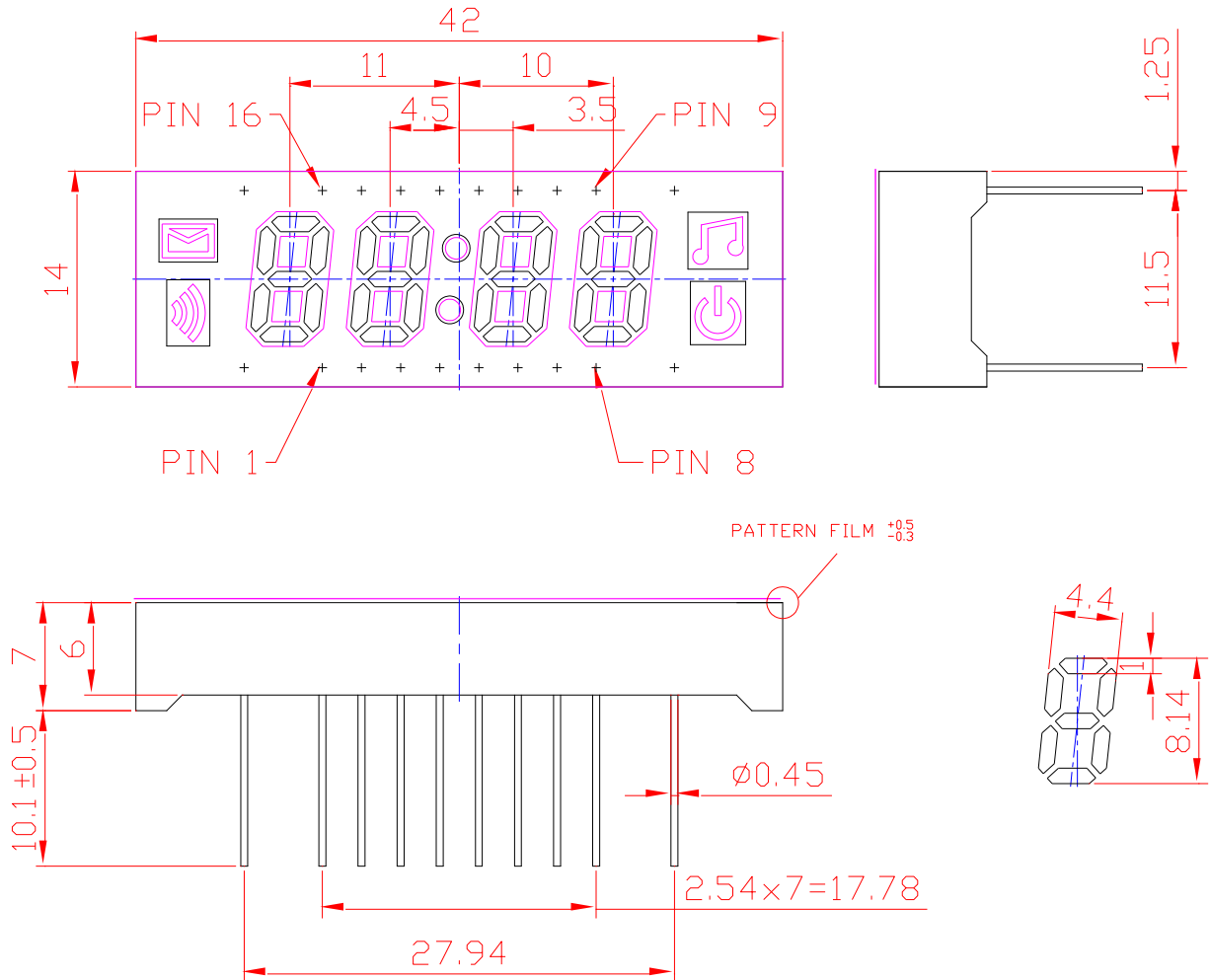
DESCRIPTION

The LTG-1163M is a 0.32 inch (8.14 mm) height multiplex digit seven-segment with several icon graphics display. This device uses AS-AlInGaP SUPER RED LED chips (AlInGaP epi on GaAs substrate), and AS-AlInGaP YELLOW chips (AlInGaP epi on GaAs substrate). The display is covered with black pattern film and white segments.

DEVICE

PART NO.	DESCRIPTION
MULIT-COLOR	COMMON ANODE
LTG-1163M	

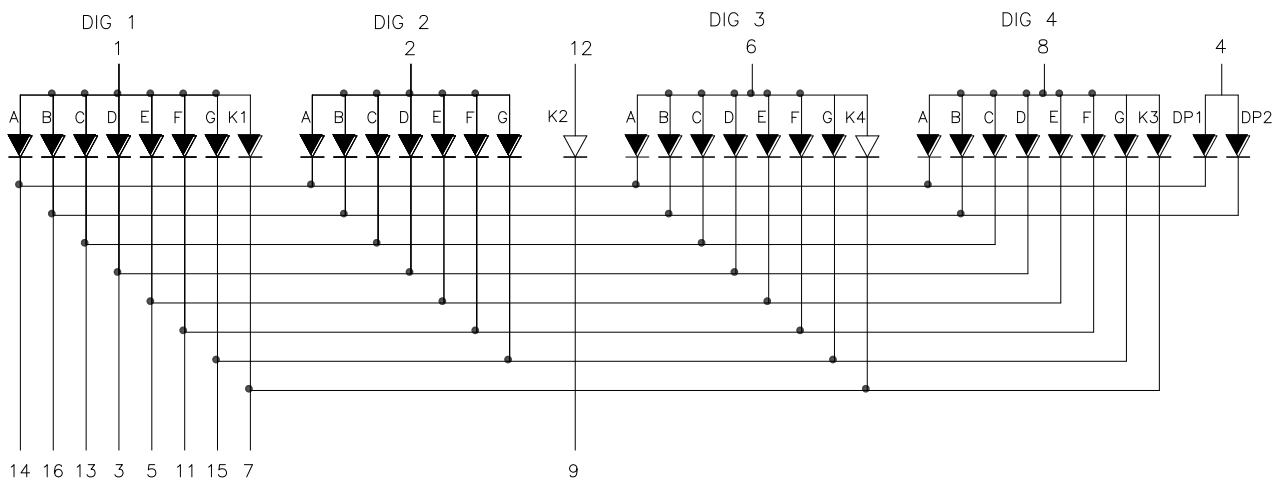
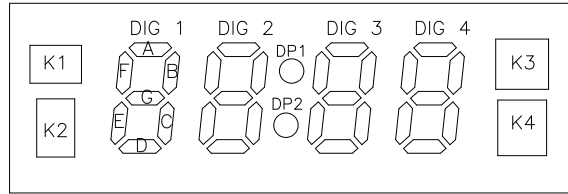
PACKAGE DIMENSIONS



TAPE

- NOTES: 1. All dimensions are in millimeters. Tolerances are ± 0.25 mm unless otherwise noted.
 2. Pin tip's shift tolerance is ± 0.4 mm.

INTERNAL CIRCUIT DIAGRAM



PIN 10 no connection

THE SING"  " IS STANDARD FOR AllnGaP SUPER RED CHIP (λ D:631nm)

THE SING"  " IS STANDARD FOR AllnGaP YEELOW CHIP (λ D:587nm)

PIN CONNECTION

NO	CONNECTION
1	COMMON ANODE DIG1,K1
2	COMMON ANODE DIG2
3	CATHODE D
4	COMMON ANODE DP1,DP2
5	CATHODE E
6	COMMON ANODE DIG3,K4
7	CATHODE K1,K4,K3
8	COMMON ANODE DIG4,K3
9	CATHODE K2
10	NO CONNECTION
11	CATHODE F
12	ANODE K2
13	CATHODE C
14	CATHODE A
15	CATHODE G
16	CATHODE B

ABSOLUTE MAXIMUM RATINGS

PARAMETER	RED	YELLOW	UNIT
Power Dissipation Per Segment	70	70	mW
Peak Forward Current Per Segment (Frequency 1Khz, 10% duty cycle)	90	60	mA
Continuous Forward Current Per Segment	25	25	mA
Forward Current Derating from 25 ⁰ C	0.33	0.33	mA/ ⁰ C
Operating Temperature Range	-35 ⁰ C to +85 ⁰ C		
Storage Temperature Range	-35 ⁰ C to +85 ⁰ C		

Solder Conditions: 1/16 inch below seating plane for 5seconds at 260⁰C,or temperature of unit (during assembly) not over max. temperature rating above

ELECTRICAL/OPTICAL CHARACTERISTICS AT Ta=25 °C**RED**

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity Per Icon	I _v		12675		μcd	I _F =10mA
Peak Emission Wavelength	λ _p		639		nm	I _F =20mA
Spectral Line Half-Width	Δλ		20		nm	I _F =20mA
Dominant Wavelength	λ _d		631		nm	I _F =20mA
Forward Voltage Per Segment	V _F		2	2.6	V	I _F =20mA
Reverse Current Per Segment* ^{NOTE 2}	I _R			100	μA	V _R =5V
Luminous Intensity Matching Ratio (Similar Light Area)	I _v -m			2:1		I _F =10mA

YELLOW

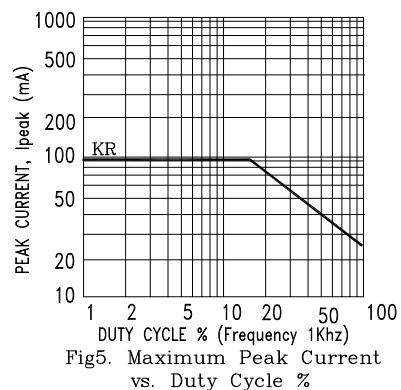
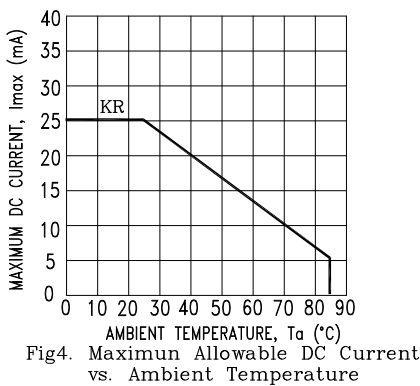
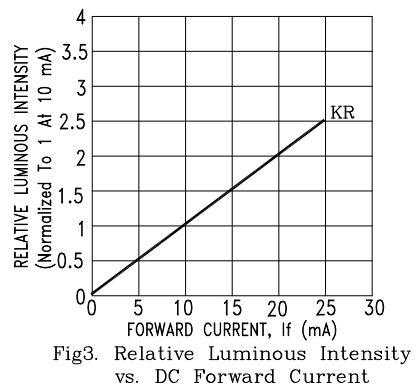
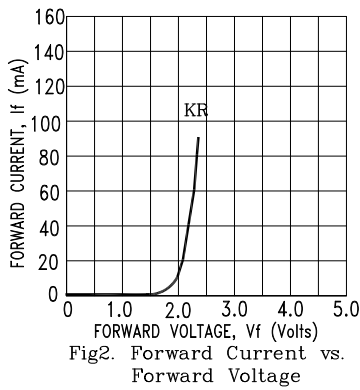
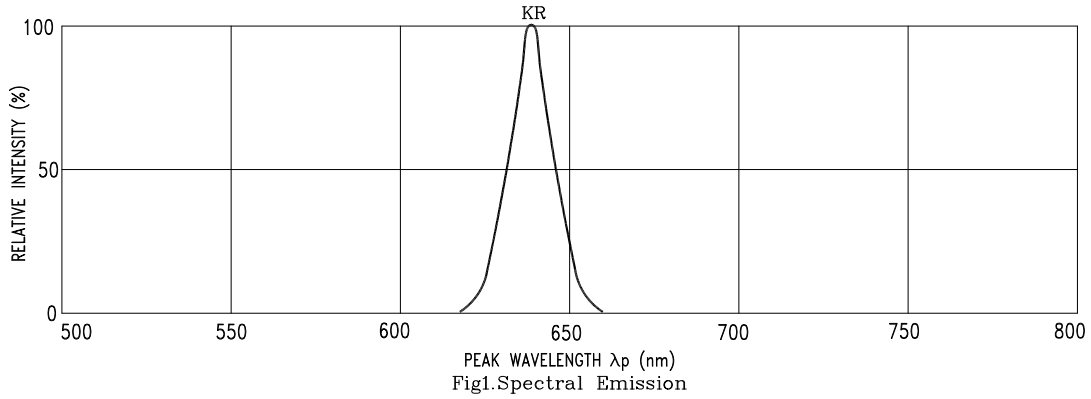
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity Per Segment	I _v		16900		μcd	I _F =10mA
Peak Emission Wavelength	λ _p		588		nm	I _F =20mA
Spectral Line Half-Width	Δλ		15		nm	I _F =20mA
Dominant Wavelength	λ _d		587		nm	I _F =20mA
Forward Voltage Per Segment	V _F		2.05	2.6	V	I _F =20mA
Reverse Current Per Segment* ^{NOTE 2}	I _R			100	μA	V _R =5V
Luminous Intensity Matching Ratio (Similar Light Area)	I _{v-m}			2:1		I _F =10mA

Note: 1. Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commission Internationale De L'Eclairage) eye-response curve.

2. Reverse voltage is only for IR test. It can not continue to operate at this situation.

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

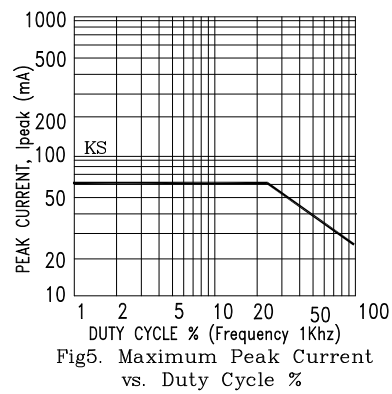
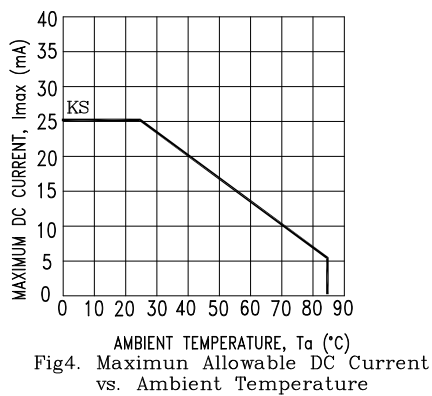
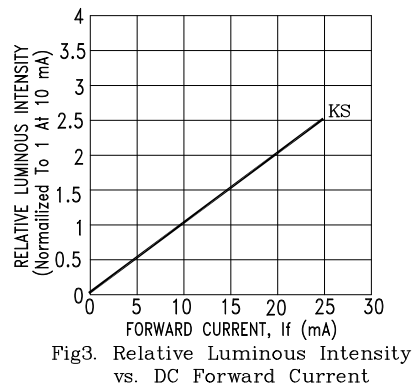
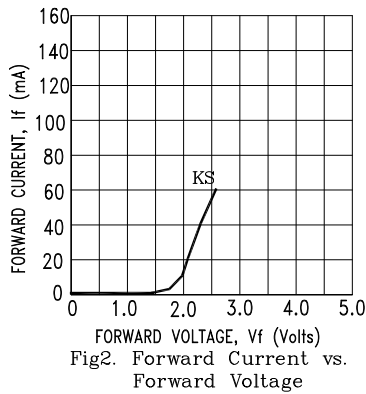
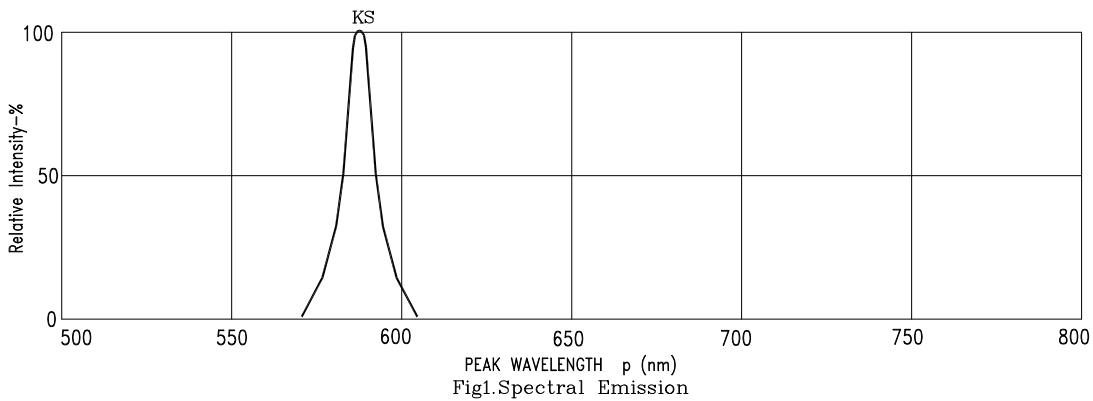
(25°C Ambient Temperature Unless Otherwise Noted)



NOTE : KR=AlInGaP SUPER RED

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)



NOTE : KS=AlInGaP YELLOW